2SD1821, 2SD1821A

Silicon NPN epitaxial planer type

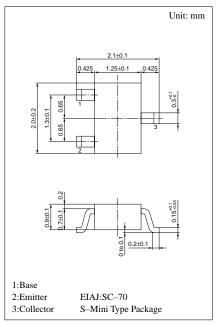
For high breakdown voltage low-frequency and low-noise amplification

Features

- $\bullet \;\;$ High collector to emitter voltage $V_{\text{CEO}}.$
- Low noise voltage NV.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit	
Collector to	2SD1821	37	150	V	
base voltage	2SD1821A	V_{CBO}	185		
Collector to	2SD1821	**	150	V	
emitter voltage	2SD1821A	V_{CEO}	185		
Emitter to base voltage		$V_{\rm EBO}$	5	V	
Peak collector current		I_{CP}	100	mA	
Collector current		I_{C}	50	mA	
Collector power dissipation		P_{C}	150	mW	
Junction temperature		T _j	150	°C	
Storage temperature		$T_{\rm stg}$	−55 ~ +150	°C	



 $\begin{array}{c} \text{Marking symbol}: P(2SD1821) \\ L(2SD1821A) \end{array}$

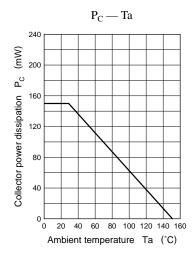
Electrical Characteristics (Ta=25°C)

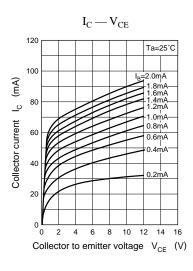
Paramete	Parameter		Conditions	min	typ	max	Unit
Collector cutoff curre	ent	I_{CBO} $V_{CB} = 100V, I_{E} = 0$				1	μА
Collector to emitter	2SD1821	***	I 100A I 0	150			3.7
voltage	2SD1821A	V_{CEO}	$I_{\rm C} = 100 \mu A, I_{\rm B} = 0$	185			V
Emitter to base voltage		V _{EBO}	$I_E = 10\mu A, I_C = 0$	5			V
Forward current transfer ratio		h _{FE} *	$V_{CE} = 5V, I_{C} = 10mA$	130		330	
Collector to emitter saturation voltage		V _{CE(sat)}	$I_{\rm C} = 30 {\rm mA}, I_{\rm B} = 3 {\rm mA}$			1	V
Transition frequency		f_{T}	$V_{CB} = 10V, I_{E} = -10mA, f = 200MHz$		150		MHz
Collector output capacitance		C _{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$		2.3		pF
Noise voltage		NV	$V_{CE} = 10V, I_C = 1mA, G_V = 80dB$ $R_g = 100k\Omega, Function = FLAT$		150		mV

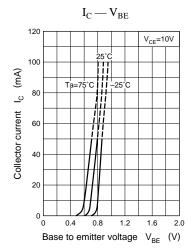
*hFE Rank classification

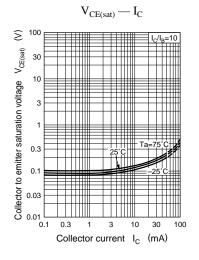
Ra	nk	R	S		
h	FE	130 ~ 220	185 ~ 330		
Marking	2SD1821	PR	PS		
Symbol	2SD1821A	LR	LS		

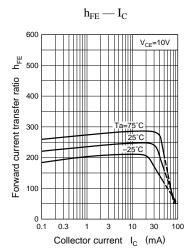
Panasonic 1

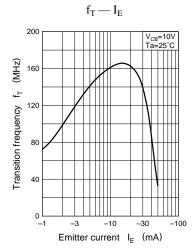


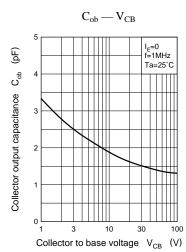












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